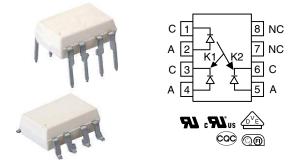
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Vishay Semiconductors

Linear Optocoupler, High Gain Stability, Wide Bandwidth



LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The IL300 linear optocoupler consists of an AlGaAs infrared emitter irradiating an output PIN photodiode and a feedback photodiode. The feedback photodiode captures a percentage of the emitter's flux and generates a control signal (I_{P1}) that can be used to keep the emitter output constant by adjusting the emitter forward current. This compensates for the emitter's non-linear, time, and temperature characteristics. The output PIN photodiode produces an output signal (IP2) that is linearly related to the servo optical flux created by the emitter.

The time and temperature stability of the input-output coupler gain (K3) is insured by using matched PIN photodiodes that accurately track the output flux of the emitter.

FEATURES

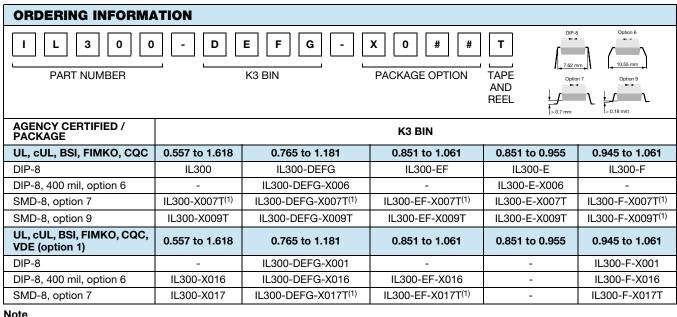
- Couples AC and DC signals
- High gain stability, ± 0.005 %/°C typically
- Low input-output capacitance
- Isolation rated voltage 4420 V_{RMS}
- Internal insulation distance, > 0.4 mm
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Power supply feedback voltage / current
- Medical sensor isolation
- Audio signal interfacing
- Isolated process control transducers
- Digital telephone isolation

AGENCY APPROVALS

- UL 1577
- <u>cUL</u>
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI
- FIMKO
- <u>CQC</u>



Note

⁽¹⁾ Also available in tubes, do not put "T" on the end

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Power dissipation		P _{diss}	100	mW			
Forward current		١ _F	60	mA			
Surge current (pulse width < 10 μ s)		I _{PK}	250	mA			
Reverse voltage		V _R	5	V			
Junction temperature		Tj	125	°C			
OUTPUT							
Power dissipation		P _{diss}	50	mW			
Reverse voltage		V _R	50	V			
Junction temperature		Tj	125	°C			
COUPLER							
Total package dissipation at 25 °C		P _{tot}	150	mW			
Storage temperature		T _{stg}	-55 to +150	°C			
Operating temperature		T _{amb}	-55 to +100	°C			

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT (LED EMITTER)						
Forward voltage	I _F = 10 mA	V _F	-	1.4	1.5	V
Reverse current	$V_R = 5 V$	I _R	-	1	-	μA
Junction capacitance	$V_F = 0 V$, f = 1 MHz	Cj	-	26	-	pF
OUTPUT						
Dark current	$V_{det} = -15 \text{ V}, \text{ I}_F = 0 \text{ A}$	Ι _D	-	1	25	nA
Open circuit voltage	I _F = 10 mA	V _D	-	500	-	mV
Short circuit current	I _F = 10 mA	I _{SC}	-	90	-	μA
Junction capacitance	$V_F = 0 V$, f = 1 MHz	Cj	-	12	-	pF
COUPLER						
Input-output capacitance	$V_F = 0 V$, f = 1 MHz		-	1	-	pF
K1, servo gain (I _{P1} /I _F)	$I_F = 10 \text{ mA}, V_{det} = -15 \text{ V}$	K1	0.005	0.009	0.015	
Servo photocurrent ⁽¹⁾⁽²⁾	$I_{F} = 10 \text{ mA}, V_{det} = -15 \text{ V}$	I _{P1}	-	90	-	μA
K2, forward gain (I_{P2}/I_F)	$I_F = 10$ mA, $V_{det} = -15$ V	K2	0.005	0.009	0.015	
Forward current	$I_{F} = 10 \text{ mA}, V_{det} = -15 \text{ V}$	I _{P2}	-	90	-	μA
K3, transfer gain (K2/K1) ⁽¹⁾⁽²⁾	$I_{F} = 10 \text{ mA}, V_{det} = -15 \text{ V}$	K3	0.56	1	1.65	K2/K1
Transfer gain stability	I _F = 10 mA, V _{det} = -15 V, T _{amb} = 0 °C to 75 °C	Δ K 3/ΔT _A	-	± 0.005	± 0.15	%/°C
Transfer gain linearity	$I_F = 2 \text{ mA to } 10 \text{ mA}$	ΔK3	-	± 0.25	-	%

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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	ARAMETER TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT						
PHOTOCONDUCTIVE OPERATION							
Frequency response	I_F = 10 mA, MOD = \pm 4 mA, R_L = 50 Ω	BW (-3 db)	-	1.4	-	MHz	
Phase response at 200 kHz	$V_{det} = -15 V$		-	-45	-	0	

Notes

• Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

 $^{(1)}$ Bin sorting: K3 (transfer gain) is sorted into bins that are \pm 6 %, as follows:

Bin D = 0.765 to 0.859

Bin E = 0.851 to 0.955

Bin F = 0.945 to 1.061

Bin G = 1.051 to 1.181

K3 = K2/K1. K3 is tested at I_F = 10 mA, V_{det} = -15 V

(2) Bin categories: All IL300s are sorted into a K3 bin, indicated by an alpha character that is marked on the part. The bins range from "A" through "J".

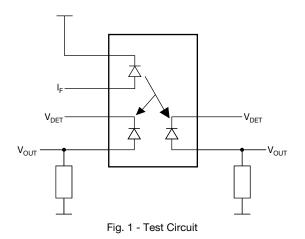
The IL300 is shipped in tubes of 50 each. Each tube contains only one category of K3. The category of the parts in the tube is marked on the tube label as well as on each individual part

(3) Category options: standard IL300 orders will be shipped from the categories that are available at the time of the order. Any of the ten categories may be shipped. For customers requiring a narrower selection of bins, the bins can be grouped together as follows: IL300-DEFG: order this part number to receive categories D, E, F, G only

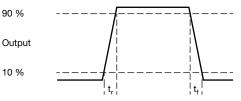
IL300-EF: order this part number to receive categories E, F only

IL300-E: order this part number to receive category E only

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	I _F = 10 mA, MOD = +2 mA,	t _r	-	0.8	-	μs
Fall time	$R_L = 10 \ k\Omega$	t _f	-	0.8	-	μs



I_F = 12 mA Input I_F = 10 mA





COMMON MODE TRANSIENT IMMUNITY						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode capacitance	$V_F = 0 V$, f = 1 MHz	C _{CM}	-	1	-	pF
Common mode rejection ratio	f = 60 Hz, R_L = 2.2 k Ω	CMRR	-	100	-	dB

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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}
Maximum transient isolation voltage		VIOTM	10 000	V _{peak}
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω
	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω
Output safety power		P _{SO}	400	mW
Input safety current		I _{SI}	275	mA
Safety temperature		Ts	175	°C
Creepage distance	DIP-8		≥ 7	mm
Clearance distance	DIF-8		≥ 7	mm
Creepage distance	DIP-8, 400 mil, option 6; SMD-8,		≥ 8	mm
Clearance distance	option 7; SMD-8, option 9		≥ 8	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

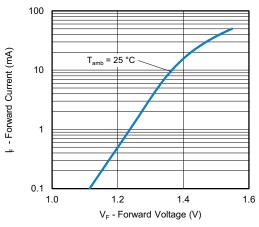


Fig. 3 - Forward Voltage vs. Forward Current

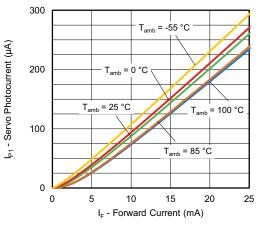


Fig. 4 - Servo Photocurrent vs. Forward Current



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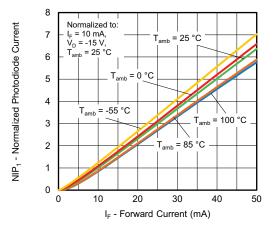


Fig. 5 - Normalized Photodiode Current vs. Forward Current

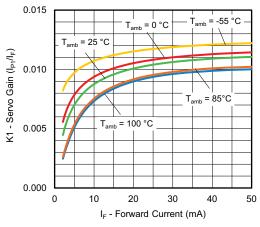


Fig. 6 - Servo Gain vs. Forward Current

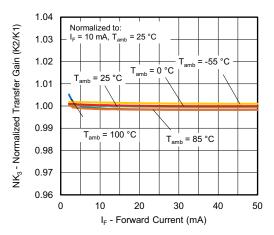


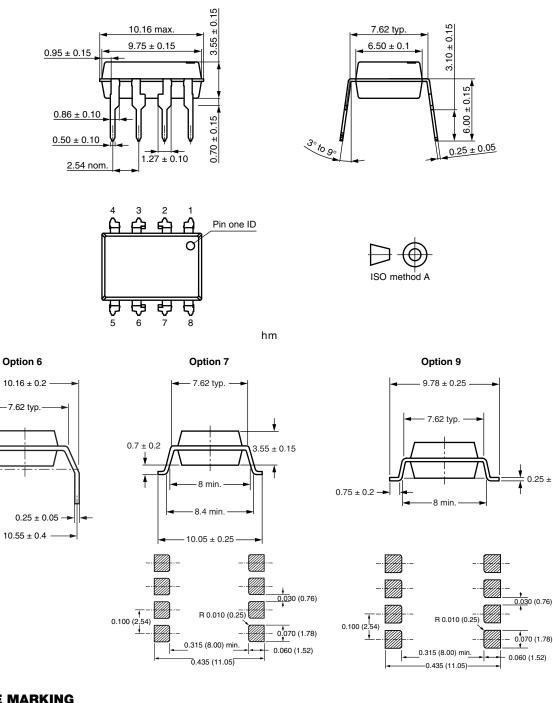
Fig. 7 - Normalized Transfer Gain vs. Forward Current

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PACKAGE DIMENSIONS (in millimeters)



PACKAGE MARKING

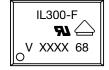


Fig. 8 - Example of IL300-F-X001

Note

• XXXX = LMC (lot marking code)

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0.25 ± 0.05

IL300

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SOLDER PROFILES

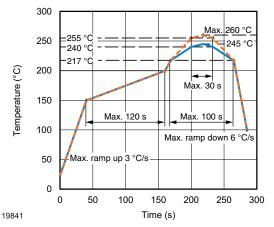


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

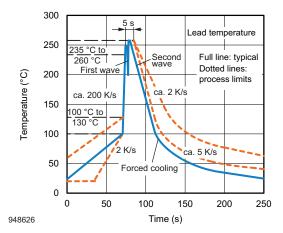


Fig. 10 - Wave Soldering Double Wave Profile According to J-STD-020 for DIP Devices

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HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited Conditions: $T_{amb} < 30$ °C, RH < 85 % Moisture sensitivity level 1, according to J-STD-020

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